AUTOMOTIVE

RoHS

COMPLIANT

Vishay Semiconductors

Bicolor SMD LED PLCC-4



19211

DESCRIPTION

These devices have been designed to meet the increasing demand for surface mounting technology.

The package of the VLMRY3420 is the PLCC-4.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

This SMD device consists of a amber and yellow chip. So it is possible to choose the color in one device.

PRODUCT GROUP AND PACKAGE DATA

Product group: LED

- Package: SMD PLCC-4 •
- Product series: bicolor
- Angle of half intensity: ± 60° ٠

FEATURES

- SMD LED with exceptional brightness
- Multicolored
- Luminous intensity categorized
- EIA and ICE standard package
- Compatible with automatic placement equipment
- Compatible with IR reflow, vapor phase and wave soldering processes according <u>GREEN</u> (5-2008)** to CECC 00802 and J-STD-020
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit $I_{Vmax}/I_{Vmin} \le 1.6$
- Preconditioning: according to JEDEC level 2a
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- · ESD-withstand voltage: up to 2 kV according to JESD22-A114-B
- AEC-Q101 qualified

APPLICATIONS

- · Automotive: backlighting in dashboards and switches
- Telecommunication: indicator and backlighting in telephone and fax
- Indicator and backlight in office equipment
- Flat backlight for LCDs, switches and symbols
- General use

PARTS TABLE				
PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY		
VLMRY3420-GS08	Amber, $I_V = (355 \text{ to } 900) \text{ mcd}$ Yellow, $I_V = (560 \text{ to } 1120) \text{ mcd}$	AllnGaP on GaAs		
VLMRY3420-GS18	Amber, $I_V = (355 \text{ to } 900) \text{ mcd}$ Yellow, $I_V = (560 \text{ to } 1120) \text{ mcd}$	AllnGaP on GaAs		

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

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For technical support, please contact: LED@vishav.com

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ABSOLUTE MAXIMUM RATINGS ¹⁾ VLMRY3420						
PARAMETER	TEST CONDIT	ION	SYMBOL	VALUE	UNIT	
Reverse voltage per diode 2)	I _R = 10 μA		V _R	5	V	
DC forward current per diode	$T_{amb} \le 65$ °	С	١ _F	50	mA	
Surge forward current per diode			I _{FSM}	0.1	А	
Power dissipation per diode			P _V	130	mW	
Junction temperature			Тj	125	°C	
Operating temperature range			T _{amb}	- 40 to + 100	°C	
Storage temperature range			T _{stg}	- 40 to + 100	°C	
Thermal resistance junction/ ambient	Mounted on PC board (pad size > 16 mm ²)	1 chip on 2 chips on	R _{thJA}	480 650	K/W	

Notes:

1) $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified

2) Driving the LED in reverse direction is suitable for short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ VLMRY3420, AMBER							
PARAMETER TEST CONDITION		PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 50 mA	VLMRY3420	Ι _V	355		900	mcd
Dominant wavelength	I _F = 50 mA		λ_d		617		nm
Peak wavelength	I _F = 50 mA		λρ		624		nm
Angle of half intensity	I _F = 50 mA		φ		± 60		deg
Forward voltage	I _F = 50 mA		V _F		2.1	2.6	V
Reverse current	V _R = 5 V,		I _R			10	μΑ
Junction capacitance	V _R = 0, f = 1 MHz		Cj		15		pF

Note:

1) $T_{amb} = 25 \text{ °C}$, unless otherwise specified

OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ VLMRY3420, YELLOW							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	l _F = 50 mA	VLMRY3420	Ι _V	560		1120	mcd
Dominant wavelength	l _F = 50 mA		λ_d	581	588	594	nm
Peak wavelength	I _F = 50 mA		λ _p		590		nm
Angle of half intensity	I _F = 50 mA		φ		± 60		deg
Forward voltage	l _F = 50 mA		V _F		2.1	2.6	V
Reverse current	V _R = 5 V		I _R			10	μA
Junction capacitance	V _R = 0, f = 1 MHz		Cj		15		pF

CROSSING TABLE			
VISHAY	OSRAM		
VLMRY3420	LAYT67B		



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L	LUMINOUS INTENSITY CLASSIFICATION AND GROUP COMBINATIONS ¹⁾ VLMRY3420							
		RED						
		T2 355 to 450 mcd	U1 450 to 560 mcd	U2 560 to 710 mcd	V1 710 to 900 mcd			
YELLOW	U2 560 to 710 mcd	VLMRY3420	VLMRY3420	VLMRY3420	VLMRY3420			
	V1 710 to 900 mcd	VLMRY3420	VLMRY3420	VLMRY3420	VLMRY3420			
	V2 900 to 1120 mcd	VLMRY3420	VLMRY3420	VLMRY3420	VLMRY3420			

Note:

1) Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of \pm 11 %.

COLOR CLASSIFICATION					
	DOMINANT WAVELENGTH (nm)				
GROUP	YELLOW				
	MIN.	MAX.			
1	581	584			
2	583	586			
3	585	588			
4	587	590			
5	589	592			
6	591	594			

Note:

Wavelengths are tested at a current pulse duration of 25 ms.

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

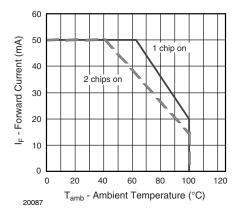


Figure 1. Forward Current vs. Ambient Temperature

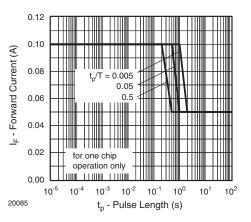


Figure 2. Forward Current vs. Pulse Duration

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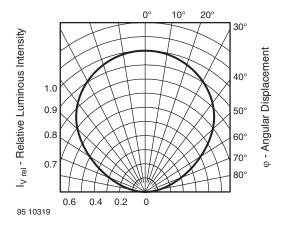


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

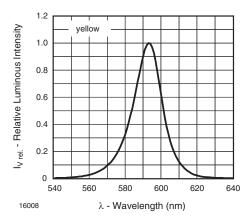


Figure 4. Relative Intensity vs. Wavelength

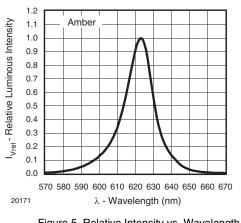


Figure 5. Relative Intensity vs. Wavelength

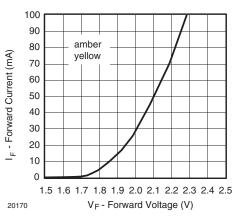


Figure 6. Relative Forward Voltage vs. Ambient Temperature

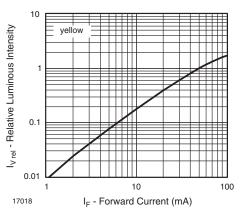


Figure 7. Relative Luminous Intensity vs. Forward Current

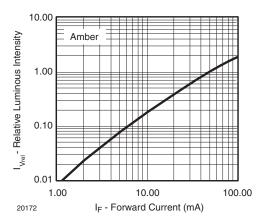


Figure 8. Relative Luminous Intensity vs. Forward Current





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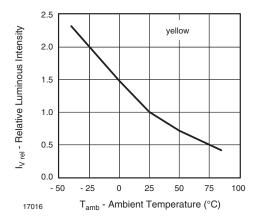


Figure 9. Rel. Luminous Intensity vs. Ambient Temperature

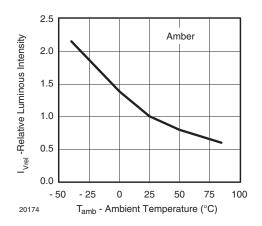


Figure 10. Rel. Luminous Intensity vs. Ambient Temperature

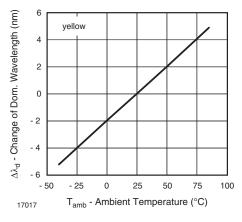


Figure 11. Change of Dominant Wavelength vs. Ambient Temperature

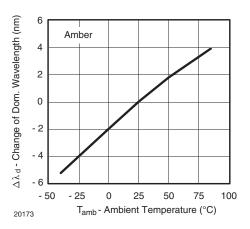


Figure 12. Change of Dominant Wavelength vs. Ambient Temperature

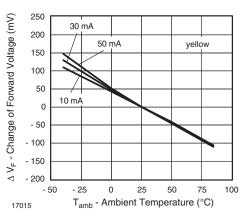


Figure 13. Change of Forward Voltage vs. Ambient Temperature

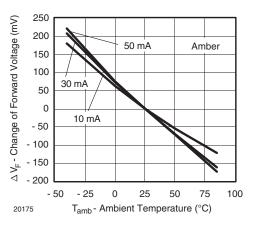


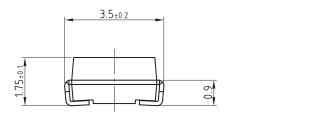
Figure 14. Change of Forward Voltage vs. Ambient Temperature

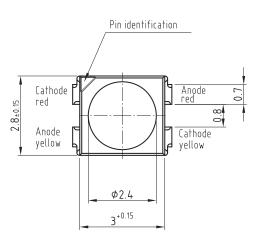
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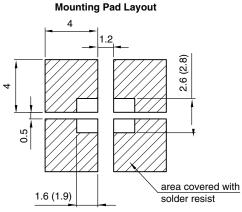
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PACKAGE DIMENSIONS in millimeters







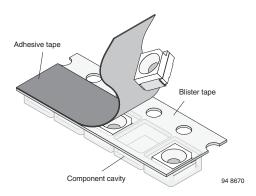


Dimensions: IR and Vaporphase (Wave Soldering)

Drawing-No.: 6.541-5057.01-4 Issue: 5; 30.05.07

METHOD OF TAPING/POLARITY AND TAPE AND REEL SMD LED (VLM.3 - SERIES) TAPING OF VLM.3...

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



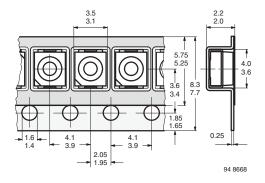


Figure 15. Tape Dimensions in mm for PLCC-2



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REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS08 (= 1500 PCS.)

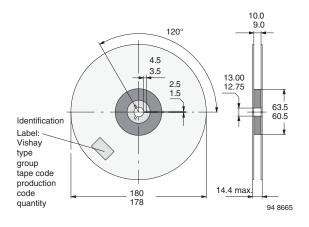


Figure 16. Reel Dimensions - GS08

SOLDERING PROFILE

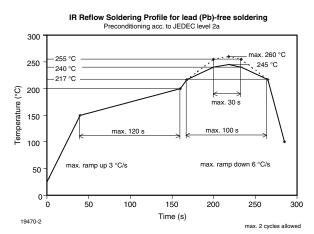


Figure 18. Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020)

REEL PACKAGE DIMENSION IN MILLIMETERS FOR SMD LEDS, TAPE OPTION GS18 (= 8000 PCS.) PREFERRED

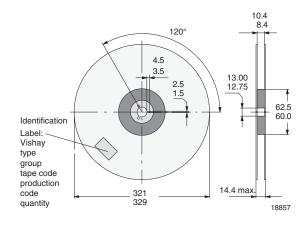


Figure 17. Reel Dimensions - GS18

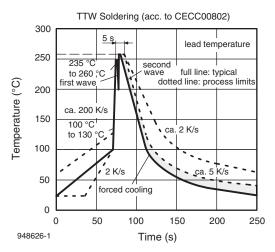
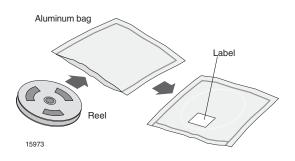


Figure 19. Double Wave Soldering of Opto Devices (all Packages)

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DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminium bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity \leq 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

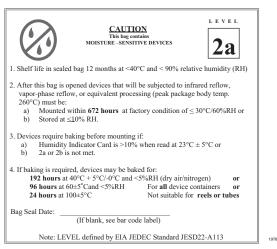
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C/ - 0 °C and < 5 % RH (dry air/ nitrogen) or

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.



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